



SN74ALVCH16245

SCES015M-JULY 1995-REVISED JUNE 2015

SN74ALVCH16245 16-Bit Bus Transceiver With 3-State Outputs

Technical

Documents

Sample &

Buv

1 Features

- Member of the Texas Instruments Widebus™ Family
- Operates From 1.65 V to 3.6 V
- Max t_{pd} of 3 ns at 3.3 V
- ±24-mA Output Drive at 3.3 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup or Pulldown Resistors
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

Applications 2

- Cable Modem Termination Systems
- Servers
- LED Displays
- **Network Switches**
- **Telecom Infrastructure**
- Motor Drivers
- I/O Expanders

3 Description

Tools &

Software

This 16-bit (dual-octal) noninverting bus transceiver is designed for 1.65-V to 3.6-V V_{CC} operation.

Support &

Community

20

The SN74ALVCH16245 device is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (OE) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic high or low level applied to prevent excess I_{CC} and I_{CCZ}.

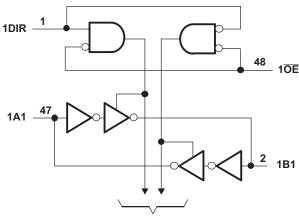
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

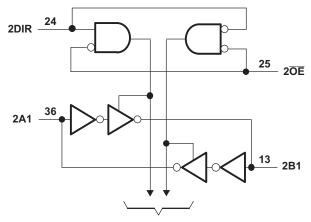
Device	Inform	nation	(1)
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PART NUMBER	PACKAGE	BODY SIZE (NOM)						
SN74ALVCH16245ZRD	BGA MICROSTAR JUNIOR (56)	4.50 mm × 7.00 mm						
SN74ALVCH16245ZQL	BGA MICROSTAR JUNIOR (54)	5.50 mm × 8.00 mm						
SN74ALVCH16245DGG	TSSOP (48)	6.10 mm × 12.50 mm						
SN74ALVCH16245DGV	TVSOP (48)	4.40 mm × 9.70 mm						
SN74ALVCH16245DL	SSOP (48)	7.50 mm × 15.80 mm						

(1) For all available packages, see the orderable addendum at the end of the data sheet.



To Seven Other Channels



To Seven Other Channels



Logic Diagram (Positive Logic)

1

2

3 4

5 6

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6.1

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6.3 6.4

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision L (November 2005) to Revision M

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Added ESD Rating table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section. 1

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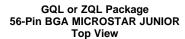
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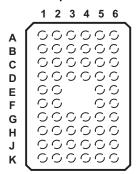
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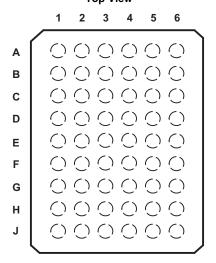
5 Pin Configuration and Functions

		_	_	1
1DIR	1	U	48] 1 <u>0</u> E
1B1 [2		47] 1A1
1B2 [3		46] 1A2
GND [4		45	GND
1B3 [5		44] 1A3
1B4 [6		43] 1A4
Vcc	7		42	V _{cc}
1B5 🛛	8		41] 1A5
1B6 [9		40] 1A6
GND [10		39] GND
1B7 [11		38] 1A7
1B8 [12		37] 1A8
2B1 🛛	13		36] 2A1
2B2 🛛	14		35] 2A2
GND [15		34] GND
2B3 [16		33] 2A3
2B4 [17		32] 2A4
V _{CC} [18		31] V _{CC}
2B5 [19		30] 2A5
2B6 🛛	20		29] 2A6
GND [21		28] GND
2B7 [22		27	2A7
2B8 [23		26] 2A8
2DIR [24		25] 2 <u>0E</u>





GRD or ZRD Package 54-Pin BGA MICROSTAR JUNIOR Top View



Pin Functions

PIN					
NAME	TSSOP, TVSOP, SSOP	FBGA (56)	FBGA (54)	I/O	DESCRIPTION
1A1	47	B5	A6	I/O	Transceiver I/O pin
1A2	46	B6	B5	I/O	Transceiver I/O pin
1A3	44	C5	B6	I/O	Transceiver I/O pin
1A4	43	C6	C5	I/O	Transceiver I/O pin
1A5	41	D5	C6	I/O	Transceiver I/O pin
1A6	40	D6	D5	I/O	Transceiver I/O pin
1A7	38	E5	D6	I/O	Transceiver I/O pin
1A8	37	E6	E5	I/O	Transceiver I/O pin
2A1	36	F6	E6	I/O	Transceiver I/O pin
2A2	35	F5	F5	I/O	Transceiver I/O pin
2A3	33	G6	F6	I/O	Transceiver I/O pin

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Pin Functions (continued)

PIN					
NAME	TSSOP, TVSOP, SSOP	FBGA (56)	FBGA (54)	I/O	DESCRIPTION
2A4	32	G5	G5	I/O	Transceiver I/O pin
2A5	30	H6	G6	I/O	Transceiver I/O pin
2A6	29	H5	H5	I/O	Transceiver I/O pin
2A7	27	J6	H6	I/O	Transceiver I/O pin
2A8	26	J5	J6	I/O	Transceiver I/O pin
1DIR	1	A1	A3	Ι	Direction control. When high, the signal propagates from A to B. When low, the signal propagates from B to A.
10E	48	A6	A4	-	Output enable
2DIR	24	K1	J3	Ι	Direction control. When high, the signal propagates from A to B. When low, the signal propagates from B to A.
20E	25	K6	J4		Output enable
1B1	2	B2	A1	I/O	Transceiver I/O pin
1B2	3	B1	B2	I/O	Transceiver I/O pin
1B3	5	C2	B1	I/O	Transceiver I/O pin
1B4	6	C1	C2	I/O	Transceiver I/O pin
1B5	8	D2	C1	I/O	Transceiver I/O pin
1B6	9	D1	D2	I/O	Transceiver I/O pin
1B7	11	E2	D1	I/O	Transceiver I/O pin
1B8	12	E1	E2	I/O	Transceiver I/O pin
2B1	13	F1	E1	I/O	Transceiver I/O pin
2B2	14	F2	F2	I/O	Transceiver I/O pin
2B3	16	G1	F1	I/O	Transceiver I/O pin
B4	17	G2	G2	I/O	Transceiver I/O pin
2B5	19	H1	G1	I/O	Transceiver I/O pin
2B6	20	H2	H2	I/O	Transceiver I/O pin
2B7	22	J1	H1	I/O	Transceiver I/O pin
2B8	23	J2	J1	I/O	Transceiver I/O pin
GND	4,10,15,21,2 8,34,39,45	B3, B4, D3, D4, G3,G4, J3, J4	D3, D4, E3,E4, F3,F4	_	Ground
V _{CC}	7,18,31,42	C3,C4,H3, H4,	C3,C4,G3,G4	_	Power pin
NC	_	A2, A3, A4,A5, K2, K3, K4, K5	A2, A5, B3, B4, H3, H4, J2, J5	_	No connect

Pin Assignments⁽¹⁾ (56-Ball GQL or ZQL Package)

				<u> </u>			
	1	2	3	4	5	6	
Α	1DIR	NC	NC	NC	NC	1 0E	
В	1B2	1B1	GND	GND	1A1	1A2	
С	1B4	1B3	V _{CC}	V _{CC}	1A3	1A4	
D	1B6	1B5	GND	GND	1A5	1A6	
E	1B8	1B7			1A7	1A8	
F	2B1	2B2			2A2	2A1	
G	2B3	2B4	GND	GND	2A4	2A3	
н	2B5	2B6	V _{CC}	V _{CC}	2A6	2A5	
J	2B7	2B8	GND	GND	2A8	2A7	
К	2DIR	NC	NC	NC	NC	2 <mark>0E</mark>	

(1) NC - No internal connection

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Pin Assignments ⁽¹⁾ (54-Ball GRD or ZRD Package)

(•••=••••=••=••=••••••••••••••••••••••										
1	2	3	4	5	6					
1B1	NC	1DIR	1 0E	NC	1A1					
1B3	1B2	NC	NC	1A2	1A3					
1B5	1B4	V _{CC}	V _{CC}	1A4	1A5					
1B7	1B6	GND	GND	1A6	1A7					
2B1	1B8	GND	GND	1A8	2A1					
2B3	2B2	GND	GND	2A2	2A3					
2B5	2B4	V _{CC}	V _{CC}	2A4	2A5					
2B7	2B6	NC	NC	2A6	2A7					
2B8	NC	2DIR	2 0E	NC	2A8					
	1B3 1B5 1B7 2B1 2B3 2B5 2B7	1 2 1B1 NC 1B3 1B2 1B5 1B4 1B7 1B6 2B1 1B8 2B3 2B2 2B5 2B4 2B7 2B6	1 2 3 1B1 NC 1DIR 1B3 1B2 NC 1B5 1B4 V _{CC} 1B7 1B6 GND 2B1 1B8 GND 2B5 2B4 V _{CC} 2B7 2B6 NC	1 2 3 4 1B1 NC 1DIR 1OE 1B3 1B2 NC NC 1B5 1B4 V _{CC} V _{CC} 1B7 1B6 GND GND 2B1 1B8 GND GND 2B3 2B2 GND GND 2B5 2B4 V _{CC} V _{CC} 2B7 2B6 NC NC	1 2 3 4 5 1B1 NC 1DIR 1OE NC 1B3 1B2 NC NC 1A2 1B5 1B4 V _{CC} V _{CC} 1A4 1B7 1B6 GND GND 1A6 2B1 1B8 GND GND 1A8 2B3 2B2 GND GND 2A2 2B5 2B4 V _{CC} V _{CC} 2A4 2B7 2B6 NC NC 2A6					

(1) NC - No internal connection

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage		-0.5	4.6	V
VI	Input voltage ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
Vo	Output voltage ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through each V _{CC} or GND			±100	mA
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 4.6 V maximum.

6.2 ESD Ratings

				VALUE	UNIT
., Electrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	2000]		
	V _(ESD)	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101, all $pins^{(2)}$	1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.3 Recommended Operating Conditions

See (1).

			MIN	MAX	UNIT
V_{CC}	Supply voltage		1.65	3.6	V
		V_{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		
VIH	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.7		V
		V_{CC} = 2.7 V to 3.6 V	2		
		V_{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
VIL	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	V
		$V_{CC} = 2.7 V \text{ to } 3.6 V$		0.8	
VI	Input voltage		0	V _{CC}	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.65 V		-4	
	1 Patrick for the stand assume of	$V_{CC} = 2.3 V$		-12	mA
I _{OH}	High-level output current	$V_{CC} = 2.7 V$		-12	ША
		$V_{CC} = 3 V$		-24	
		V _{CC} = 1.65 V		4	
		$V_{CC} = 2.3 V$		12	mA
I _{OL}	Low-level output current	$V_{CC} = 2.7 V$		12	ШA
		$V_{CC} = 3 V$		24	
Δt/Δv	Input transition rise or fall rate			10	ns/V
T _A	Operating free-air temperature		-40	85	°C

 All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

6.4 Thermal Information⁽¹⁾

THERMAL METRIC ⁽¹⁾		SN74ALVCH16245					
		DGG (TSSOP) ⁽²⁾	DGV (TVSOP) ⁽²⁾	DL (SSOP) ⁽²⁾	GQL/ZQL (BGA MICROSTAR JUNIOR) ⁽²⁾	GRD/ZRD (BGA MICROSTAR JUNIOR) ⁽²⁾	UNIT
		48 PINS	48 PINS	48 PINS	56 PINS	54 PINS	
R_{\thetaJA}	Junction-to-ambient thermal resistance	70	58	63	42	36	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

(2) The package thermal impedance is calculated in accordance with JESD 51-7.

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6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾ MAX	UNIT
	I _{OH} = -100 μA	1.65 V to 3.6 V	$V_{CC} - 0.2$		
V _{OH} V _{OH} V _{OL} V _{OL} V _{OL} V _{OL} V _{OL} V _{OL} V _{OL} V _{OL} V _{OL} V _O V _O V _O V _O V _O V _O V _O V _O	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
	$I_{OH} = -6 \text{ mA}$	2.3 V	2		
V _{OH}		2.3 V	1.7		V
	$I_{OH} = -12 \text{ mA}$	2.7 V	2.2		
		3 V	2.4		
$V_{OH} = \frac{ O_H = -100 \ \mu A}{ O_H = -4 \ m A} = \frac{1.65 \ V}{1.65 \ V} = \frac{2.3 \ V}{2.7 \ V} + \frac{2.3 \ V}{2.7 \ V} = \frac{2.3 \ V}{3 \ V} = \frac{2.3 \ V}{3 \ V} = \frac{2.7 \ V}{3 \ V} = \frac{2.7 \ V}{3 \ V} = \frac{2.7 \ V}{3 \ V} = \frac{2.3 \ V}{2.7 \ V} = \frac{2.3 \ V}{2.3 \ V} = \frac{2.3 \ V}{1.6 \ V} = 2.3 \ V$	3 V	2			
	I _{OL} = 100 μA	1.65 V to 3.6 V		0.2	
	I _{OL} = 4 mA	1.65 V		0.45	
V	I _{OL} = 6 mA	2.3 V		0.4	V
VOL	$1 - 12 m^{1}$	2.3 V		0.7	v
		2.7 V		0.4	
	I _{OL} = 24 mA	3 V		0.55	
l _l	$V_{I} = V_{CC} \text{ or } GND$	3.6 V		±5	μA
	V ₁ = 0.58 V	1.65 V	25		
	V ₁ = 1.07 V	1.65 V	-25		
	$V_1 = 0.7 V$	2.3 V	45		
I _{I(hold)}	$V_{I} = 1.7 V$	2.3 V	-45		μA
	V ₁ = 0.8 V	3 V	75		
	$V_1 = 2 V$	3 V	-75		
	$V_1 = 0$ to 3.6 V ⁽²⁾	3.6 V		±500	
$I_{OZ}^{(3)}$	$V_{O} = V_{CC}$ or GND	3.6 V		±10	μA
I _{CC}	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	3.6 V		40	μA
ΔI _{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	3 V to 3.6 V		750	μA
C _i Control inputs	$V_{I} = V_{CC}$ or GND	3.3 V		4	pF
C _{io} A or B ports	$V_{O} = V_{CC}$ or GND	3.3 V		8	pF

(1) All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$. (2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

(3) For I/O ports, the parameter I_{OZ} includes the input leakage current.

6.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7)

PARAMETER	FROM	TO (OUTPUT)	V _{CC} = 1.8 V	V _{CC} = ± 0.2	2.5 V 2 V	V _{cc} =	2.7 V	V _{CC} = ± 0.3	3.3 V 3 V	UNIT
	(INPUT)	(001-01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	B or A	See ⁽¹⁾	1	3.7		3.6	1	3	ns
t _{en}	ŌĒ	A or B	See ⁽¹⁾	1	5.7		5.4	1	4.4	ns
t _{dis}	OE	A or B	See ⁽¹⁾	1	5.2		4.6	1	4.1	ns

(1) This information was not available at the time of publication.

6.7 Operating Characteristics

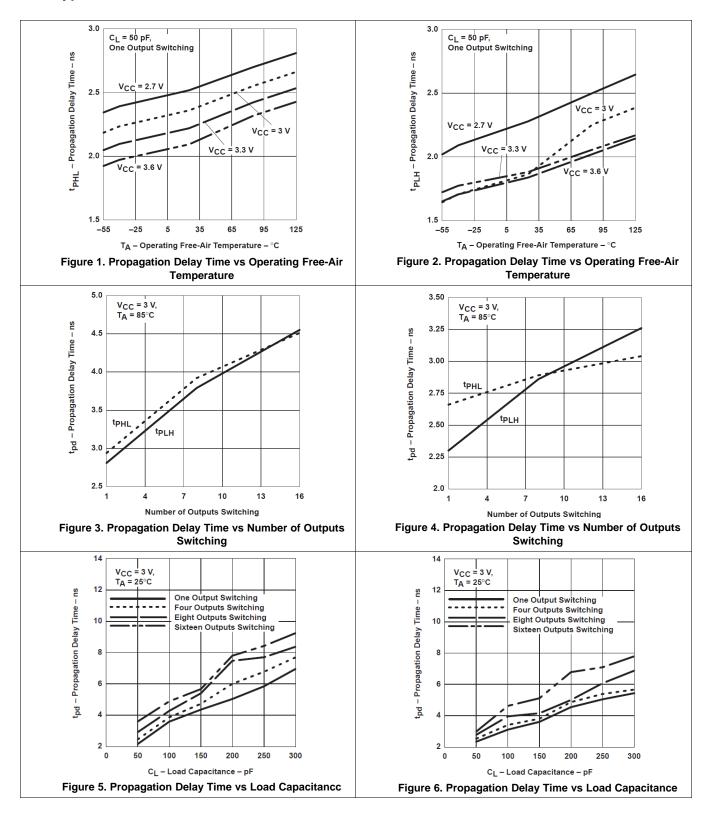
 $T_A = 25^{\circ}C$

PARAMETER		TEST C	ONDITIONS	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT	
		1231 00	JIDHIONS	ТҮР	ТҮР	TYP	UNIT	
0	Power dissipation	Outputs enabled	C 50 pF	£ 40 MU	See ⁽¹⁾	22	29	~ Г
C _{pd}		Outputs disabled	C _L = 50 pF,	f = 10 MHz	See ⁽¹⁾	4	5	рF

(1) This information was not available at the time of publication.

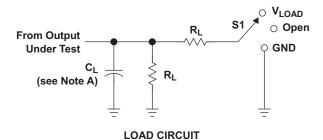


6.8 Typical Characteristics



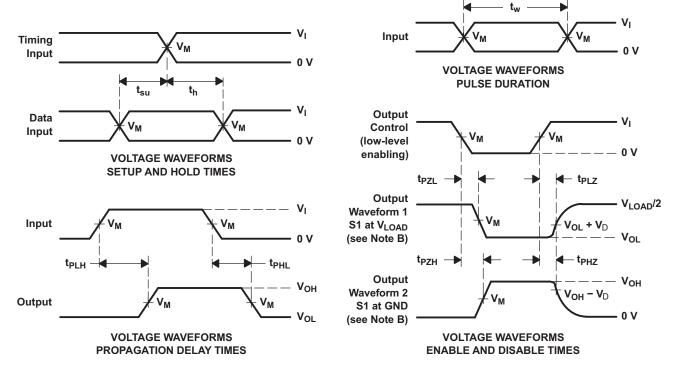
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7 Parameter Measurement Information



TEST	S1
t _{pd}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

	IN	PUT	N	V	0	P	M	
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	RL	VD	
1.8 V	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V	
2.5 V ± 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V	
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	
3.3 V ± 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR≤ 10 MHz, Z_0 = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 7. Load Circuit and Voltage Waveforms

ISTRUMENTS



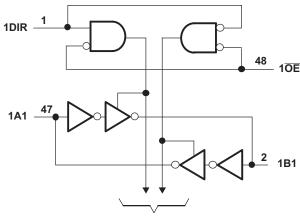
8 Detailed Description

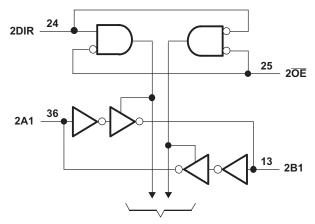
The SN74ALVCH16245 device is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (\overline{OE}) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic high or low level applied to prevent excess I_{CC} and I_{CCZ}.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

8.2 Functional Block Diagrams





To Seven Other Channels

To Seven Other Channels

8.3 Feature Description

The input tolerance of 5.5V inputs allows the device to be used in down voltage translation applications as well for example if translation is required from 5 V to 3.3 V or 1.8 V. Also bus hold on data inputs eliminates the need for external pullup or pulldown resistors to be used, enabling customer to save board space and system cost.

8.4 Device Functional Modes

Table 1 lists the functional modes for SN74ALVCH16245.

INP	UTS						
OE	DIR	OPERATION					
L	L	B data to A bus					
L	Н	A data to B bus					
Н	Х	Isolation					

Table 1. Function Table



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

SN74ALVCH16245A is a high-drive CMOS device that can be used for a multitude of bus interface type applications where output drive or PCB trace length is a concern. The inputs can accept voltages to 5.5 V at any valid V_{CC} making it ideal for down translation.

9.2 Typical Application

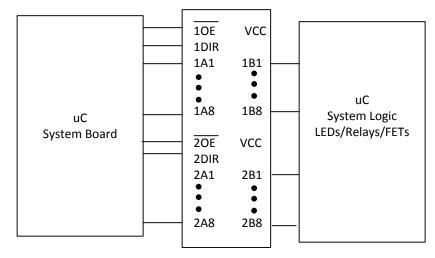


Figure 8. Typical Application Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

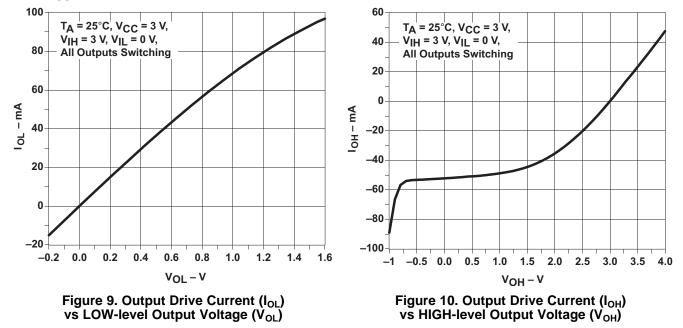
9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - For rise time and fall time specification, see Switching Characteristics
 - For specified high and low levels, see (V_{IH} and V_{IL}) in the *Electrical Characteristics* table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V₁ max) in the Absolute Maximum Ratings table at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed (I_O max) per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the *Recommended Operating Conditions* table.
 - Outputs should not be pulled above V_{CC}.



Typical Application (continued)

9.2.3 Application Curves



10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Absolute Maximum Ratings* table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a singlesupply, a 0.1- μ F capacitor is recommended. If there are multiple V_{CC} terminals then 0.01- μ F or 0.022- μ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. Multiple bypass capacitors may be paralleled to reject different frequencies of noise. The bypass capacitor should be installed as close to the power terminal as possible for the best results.

11 Layout

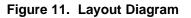
11.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 11 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient.

11.2 Layout Example







12 Device and Documentation Support

12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.2 Trademarks

Widebus, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



17-Mar-2017

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
74ALVCH16245DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16245	Samples
74ALVCH16245DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16245	Samples
74ALVCH16245ZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VH245	Samples
74ALVCH16245ZRDR	ACTIVE	BGA MICROSTAR JUNIOR	ZRD	54	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VH245	Samples
SN74ALVCH16245DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16245	Samples
SN74ALVCH16245DGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VH245	Samples
SN74ALVCH16245DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16245	Samples
SN74ALVCH16245DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16245	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



17-Mar-2017

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74ALVCH16245 :

Enhanced Product: SN74ALVCH16245-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

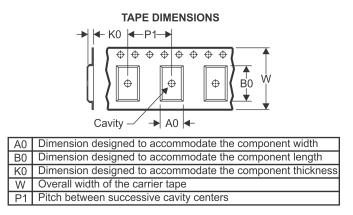
PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



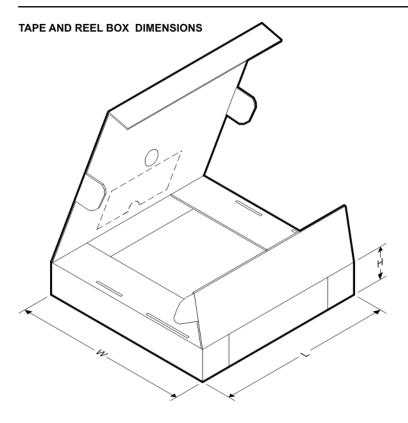
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74ALVCH16245ZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1
74ALVCH16245ZRDR	BGA MI CROSTA R JUNI OR	ZRD	54	1000	330.0	16.4	5.8	8.3	1.55	8.0	16.0	Q1
SN74ALVCH16245DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74ALVCH16245DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74ALVCH16245DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

11-Mar-2017



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74ALVCH16245ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	336.6	336.6	28.6
74ALVCH16245ZRDR	BGA MICROSTAR JUNIOR	ZRD	54	1000	336.6	336.6	28.6
SN74ALVCH16245DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74ALVCH16245DGVR	TVSOP	DGV	48	2000	367.0	367.0	38.0
SN74ALVCH16245DLR	SSOP	DL	48	1000	367.0	367.0	55.0

ZRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Falls within JEDEC MO-205 variation DD.

D. This package is lead-free. Refer to the 54 GRD package (drawing 4204759) for tin-lead (SnPb).



DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



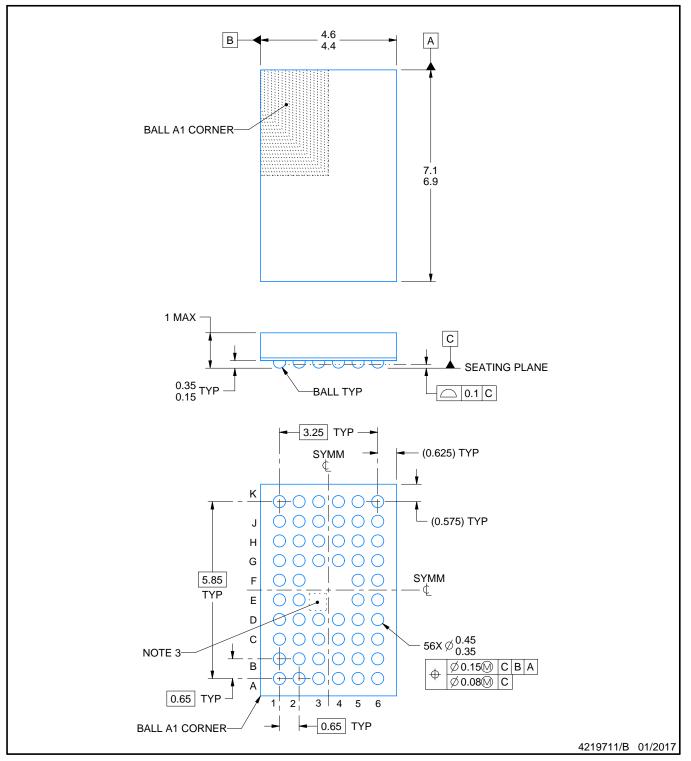
ZQL0056A



PACKAGE OUTLINE

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. No metal in this area, indicates orientation.

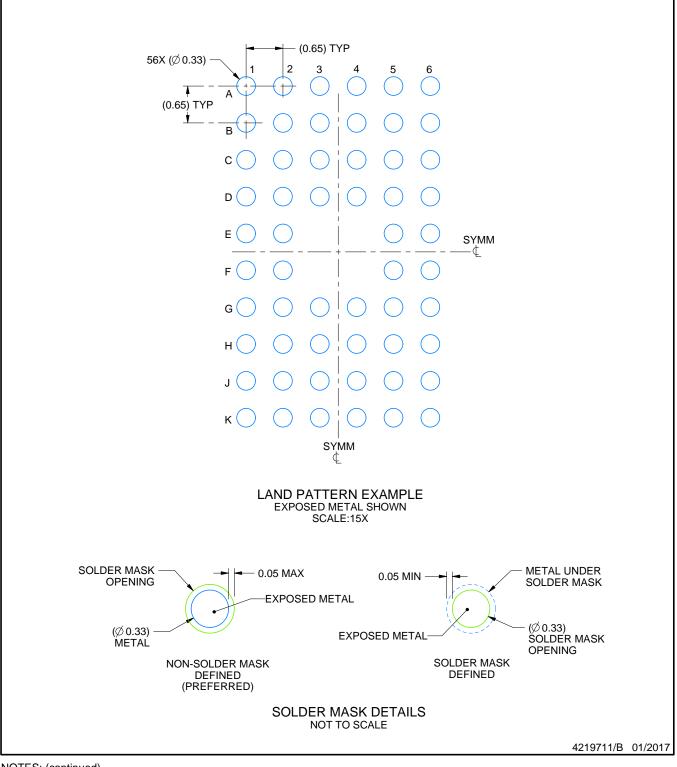


ZQL0056A

EXAMPLE BOARD LAYOUT

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).

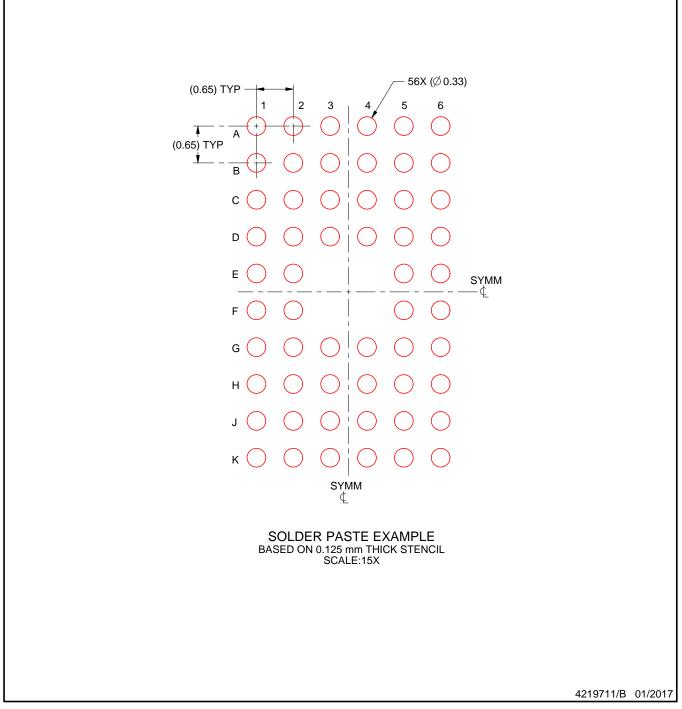


ZQL0056A

EXAMPLE STENCIL DESIGN

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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